





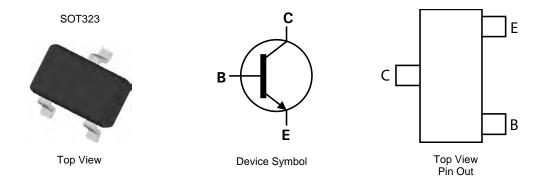
NPN SMALL SIGNAL SURFACE MOUNT TRANSISTOR IN SOT323

Features

- Low saturation voltage
- 500mW power dissipation
- I_C = 1A high Continuous Current
- Ideally suited for space / weight critical applications
- Totally Lead-Free & Fully RoHS compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

Mechanical Data

- Case: SOT323
- Case material: molded plastic. "Green" molding compound.
- UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 63
- Weight: 0.006 grams (Approximate)



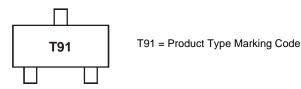
Ordering Information (Note 4)

Product	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
ZUMT491TA	T91	7	8	3,000

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
- 2. See http://www.diodes.com for more information about Diodes Incorporated's definitions of Halogen and Antimony free, "Green" and Lead-Free.
- 3. Halogen and Antimony free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at http://www.diodes.com

Marking Information





ZUMT491

Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V_{CBO}	80	V
Collector-Emitter Voltage	V _{CEO}	60	V
Emitter-Base Voltage	V_{EBO}	7	V
Continuous Collector Current	Ιc	1	A
Peak Pulse Current	Ісм	2	A
Base Current	l _B	200	mA

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Power Dissipation (Note 5)	P _D	500	mW
Thermal Resistance, Junction to Ambient (Note 5)	$R_{\theta JA}$	250	°C/W
Thermal Resistance, Junction to Leads (Note 6)	R ₀ JL	350	°C/W
Operating and Storage Temperature Range	$T_{J,}T_{STG}$	-55 to +150	°C

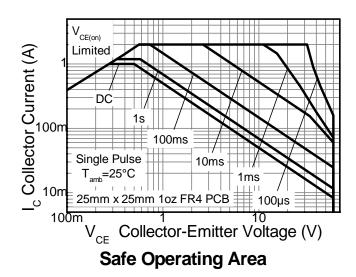
Notes:

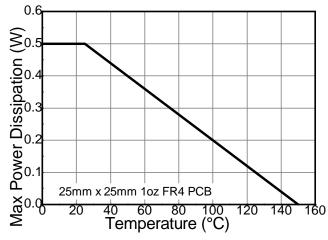
^{5.} For a device surface mounted on 25mm X 25mm FR4 PCB with high coverage of single sided 1 oz copper, in still air conditions; device measured when operating in steady state condition.

6. Thermal resistance from junction to solder-point (at the end of the leads).

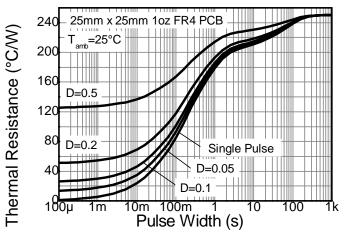


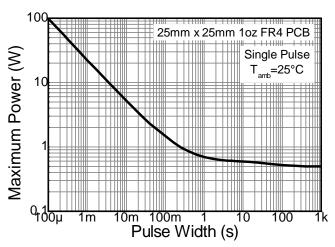
Thermal Characteristics and Derating Information





Derating Curve





Transient Thermal Impedance

Pulse Power Dissipation



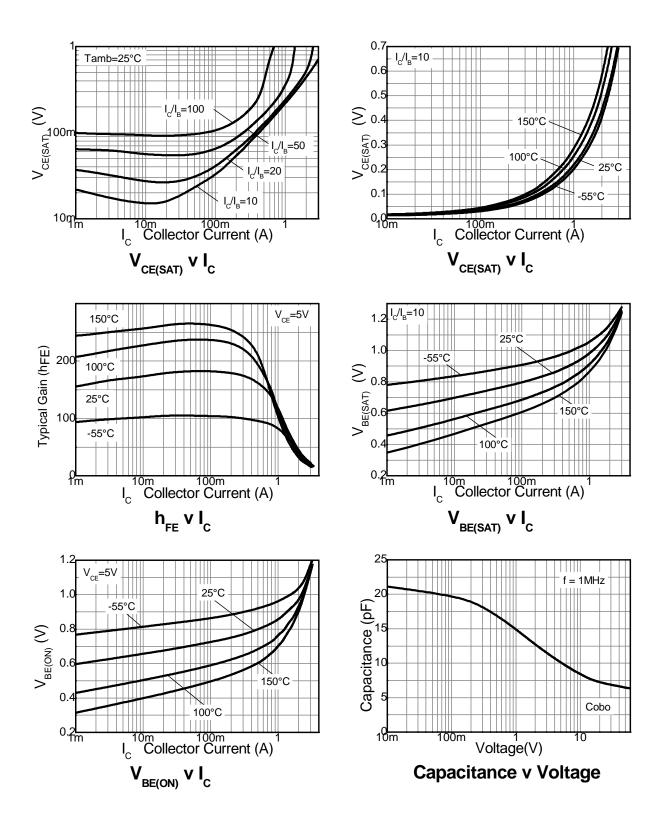
Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Max	Unit	Test Condition
OFF CHARACTERISTICS					
Collector-Base Breakdown Voltage	BV _{CBO}	80	_	V	$I_C = 100 \mu A, I_E = 0$
Collector-Emitter Breakdown Voltage (Note 7)	BV _{CEO}	60	_	V	$I_C = 10 \text{mA}, I_B = 0$
Emitter-Base Breakdown Voltage	BV _{EBO}	7	_	V	$I_E = 100 \mu A, I_C = 0$
Collector Cutoff Current	I _{CBO}	_	100	nA	V _{CB} = 60V
Collector Cutoff Current	Ices	_	100	nA	V _{CE} = 60V
Emitter Cutoff Current	I _{EBO}	_	100	nA	V _{EB} = 5V
ON CHARACTERISTICS (Note 7)					
DC Current Gain	h _{FE}	100 100 80	300 —	_	$\begin{split} I_C &= 1 \text{mA, V}_{CE} = 5.0 \text{V} \\ I_C &= 500.0 \text{mA, V}_{CE} = 5.0 \text{V} \\ I_C &= 1.0 \text{A, V}_{CE} = 5.0 \text{V} \end{split}$
Collector-Emitter Saturation Voltage	V _{CE(sat)}	_	250 500	mV	$I_C = 500 \text{mA}, I_B = 50 \text{mA}$ $I_C = 1.0 \text{A}, I_B = 100 \text{mA}$
Base-Emitter Saturation Voltage	V _{BE(sat)}	_	1100	mV	$I_C = 1.0A$, $I_B = 100mA$
Base-Emitter Turn On Voltage	V _{BE(on)}	_	1000	mV	I _C = 1.0A, V _{CE} = 5.0V

Notes: 7. Measured under pulsed conditions. Pulse width \leq 300 μ s. Duty cycle \leq 2%.

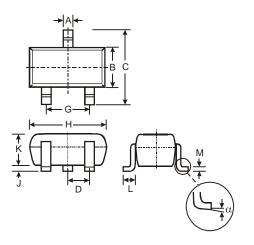


Typical Electrical Characteristics (@TA = +25°C, unless otherwise specified.)



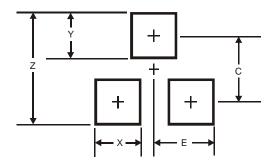


Package Outline Dimensions



SOT323					
Dim	Min	Max	Тур		
Α	0.25	0.40	0.30		
В	1.15	1.35	1.30		
С	2.00	2.20	2.10		
D	-	-	0.65		
G	1.20	1.40	1.30		
Н	1.80	2.20	2.15		
J	0.0	0.10	0.05		
K	0.90	1.00	1.00		
L	0.25	0.40	0.30		
M	0.10	0.18	0.11		
α	0°	8°	-		
All	All Dimensions in mm				

Suggested Pad Layout



Dimensions	Value (in mm)		
Z	2.8		
Х	0.7		
Y	0.9		
С	1.9		
Е	1.0		





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